

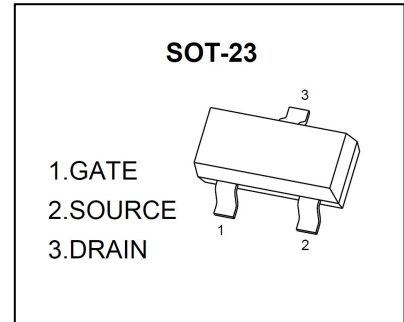


SOT-23 Plastic-Encapsulate MOSFET

CJ2302B N-Channel MOSFET

Key Performance Parameters

$V_{BR(DSS)}$	$R_{DS(on)}$ TYP	I_D
20V	29mΩ@4.5V	3.8A
	39mΩ@2.5V	



DESCRIPTION

This advanced technology has been especially tailored to minimize on-state resistance, provide superior switching performance.

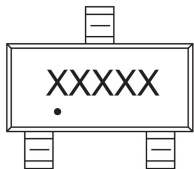
FEATURES

- High density cell design for Low RDS(on)
- Voltage controlled small signal switch
- Rugged and reliable
- High saturation current capability

APPLICATIONS

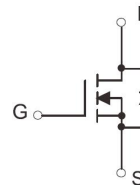
- Load Switch for Portable Devices
- DC/DC Converter

MARKING



XXXXX = 2302B
 Solid dot = Green molding compound device.

EQUIVALENT CIRCUIT



ABSOLUTE MAXIMUM RATINGS ($T_J=25^{\circ}C$ unless otherwise specified)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	20	V
Gate-Source Voltage	V_{GS}	±8	V
Continuous Drain Current	$I_D^{(5)}$	$T_A = 25^{\circ}C$	3.8
		$T_A = 75^{\circ}C$	2.9
Pulsed Drain Current	$I_{DM}^{(1)(2)}$	15.2	A
Power Dissipation	$P_D^{(1)(5)}$	1	W
Operating Junction and Storage Temperature Range	T_J, T_{stg}	-55~+150	°C

Thermal Characteristics

Parameter	Symbol	Value		Unit	
		Typ	Max		
Thermal Resistance from Junction to Ambient	$R_{\theta JA}^{(5)}$	$t \leq 10s$	104	125	°C/W
		Steady State	130	156	°C/W

Typical Characteristics

ELECTRICAL CHARACTERISTICS ($T_J=25^\circ\text{C}$ unless otherwise specified)

Static Characteristics

Parameter	Symbol	Test Condition	Value			Unit	
			Min	Typ	Max		
Drain-source breakdown voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=250\mu A$	20	-	-	V	
Zero gate voltage drain current	I_{DSS}	$V_{DS}=20V, V_{GS}=0V$	$T_J=25^\circ\text{C}$	-	-	1.0	μA
			$T_J=125^\circ\text{C}$	-	-	100	
Gate-body leakage current	I_{GSS}	$V_{GS}=\pm 8V, V_{DS}=0V$	-	-	± 100	nA	
Gate-threshold voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	0.65	0.95	1.20	V	
Static drain-source on-state resistance	$R_{DS(on)}^{(3)}$	$V_{GS}=4.5V, I_D=3.6A$	$T_J=25^\circ\text{C}$	-	29	45	m Ω
			$T_J=125^\circ\text{C}$	-	41	64	
		$V_{GS}=2.5V, I_D=3.1A$	-	39	78		
Forward transconductance	g_{FS}	$V_{DS}=5V, I_D=3.6A$	-	15	-	S	

Dynamic Characteristics⁽⁴⁾

Input capacitance	C_{iss}	$V_{GS}=0V, V_{DS}=10V,$ $f=1\text{MHz}$	-	482	-	pF
Output capacitance	C_{oss}		-	66	-	
Reverse transfer capacitance	C_{rss}		-	53	-	
Total gate charge	Q_g	$V_{GS}=4.5V, V_{DS}=10V, I_D=3.6A$	-	6.42	-	nC
Gate charge at threshold	$Q_{G(th)}$		-	0.64	-	
Gate-source charge	Q_{gs}		-	1.12	-	
Gate-drain charge	Q_{gd}		-	2.33	-	
Turn-on delay time	$t_{d(on)}$	$V_{DD}=10V, V_{GS}=4.5V,$ $I_D=3.6A, R_g=6\Omega$	-	5.6	-	ns
Turn-on rise time	t_r		-	4.4	-	
Turn-off delay time	$t_{d(off)}$		-	20.7	-	
Turn-off fall time	t_f		-	6.4	-	

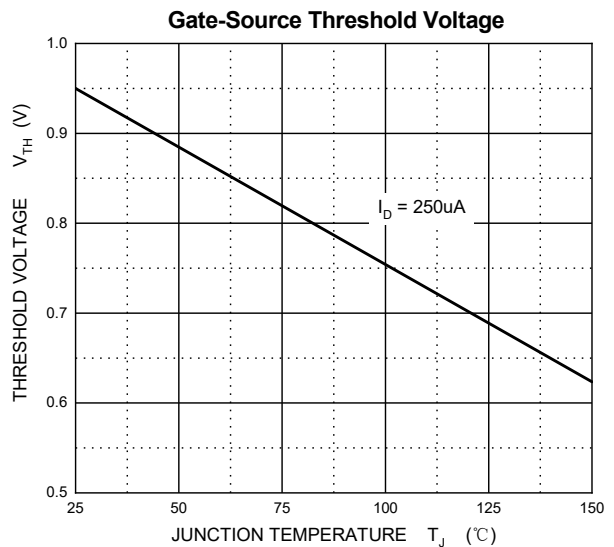
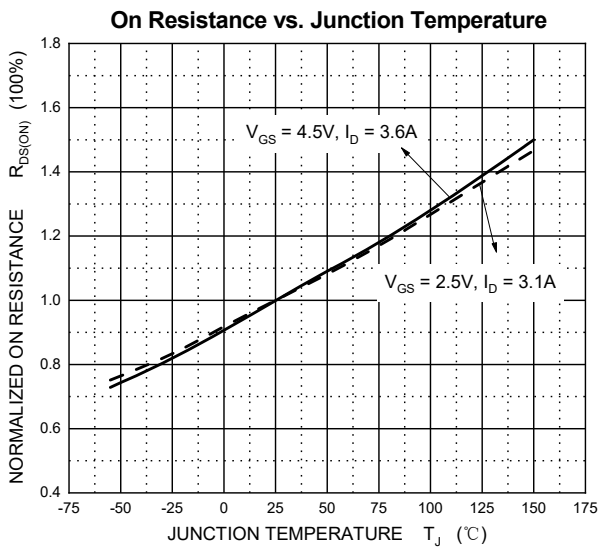
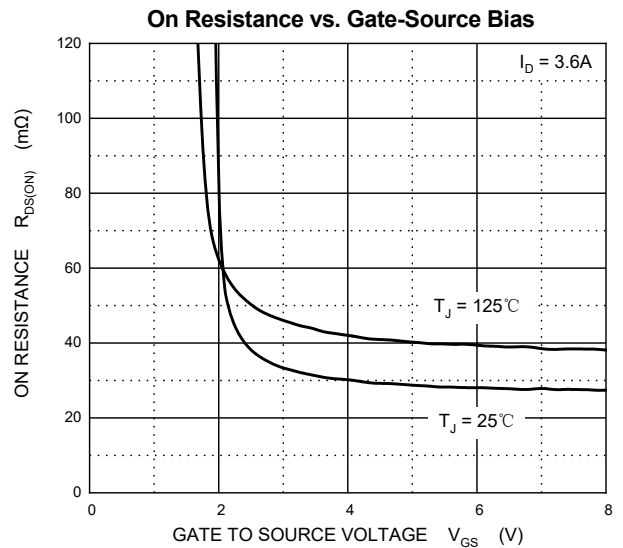
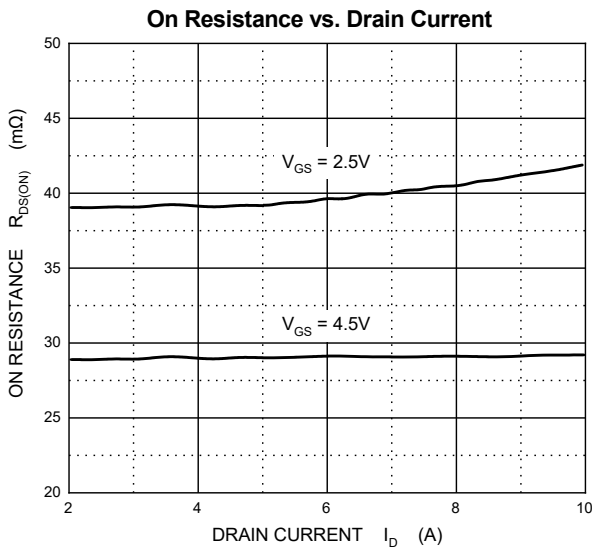
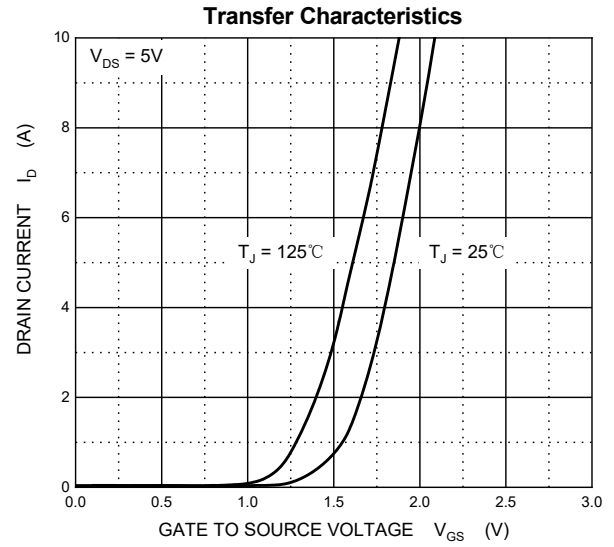
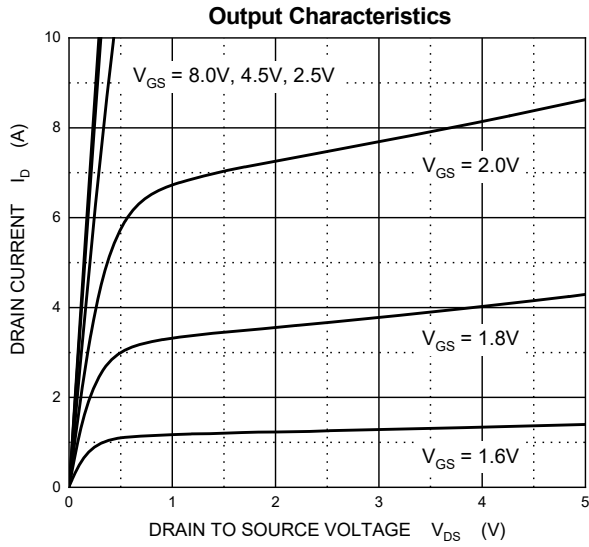
Reverse Diode Characteristics

Drain-source diode forward voltage	$V_{SD}^{(3)}$	$V_{GS}=0V, I_S=0.94A$	-	-	1.2	V
Continuous drain-source diode forward current	$I_S^{(1)}$		-	-	3.8	A
Pulsed drain-source diode forward current	$I_{SM}^{(1)(2)}$		-	-	15.2	A

Notes:

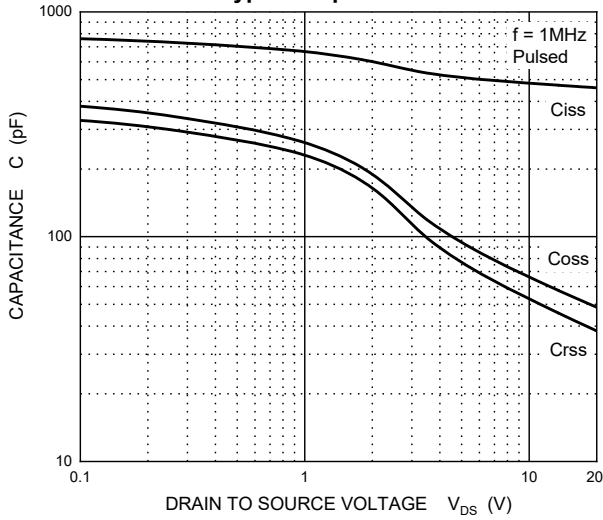
- ①. Limited only by maximum temperature allowed.
- ②. $P_W \leq 300\mu s$, Duty cycle $\leq 1\%$.
- ③. Pulse Test : Pulse Width $\leq 380\mu s$, duty cycle $\leq 2\%$.
- ④. Guaranteed by design, not subject to production.
- ⑤. Device mounted on 1 in² FR-4 board with 2oz. double-sided Copper, in a still air environment with $T_A=25^\circ\text{C}$. The current rating is based on the $t \leq 10s$ thermal resistance rating.

Typical Characteristics

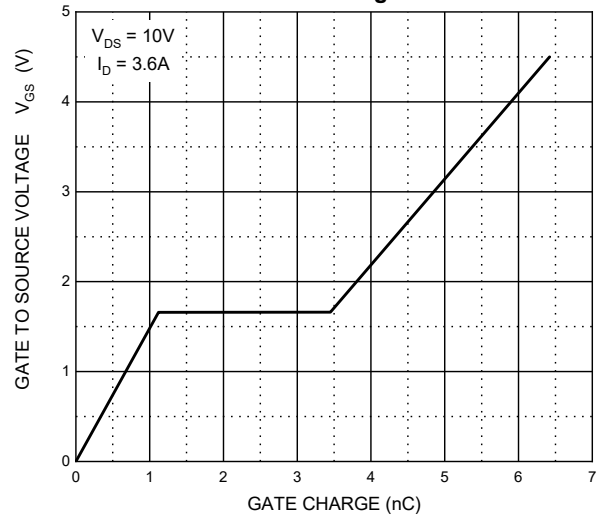


Typical Characteristics

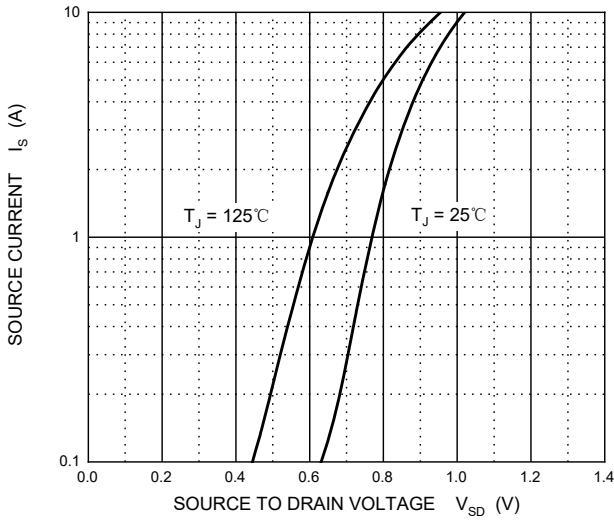
Typical Capacitances



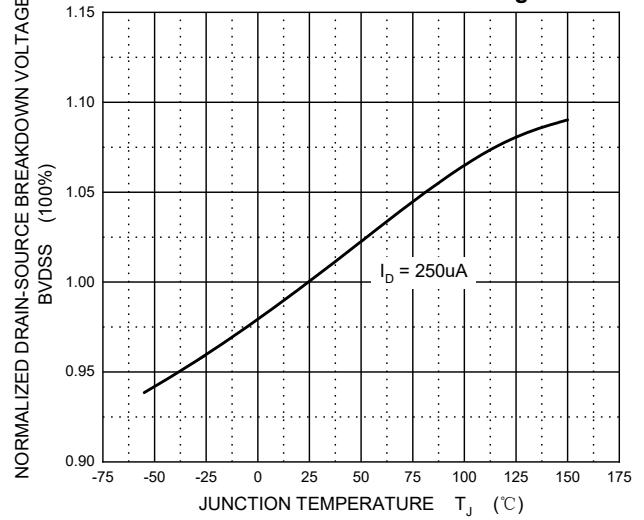
Gate Charge



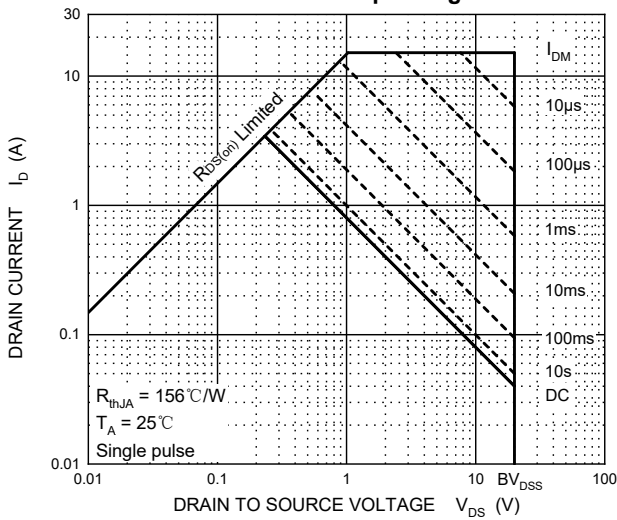
Source-Drain Diode Forward Characteristics



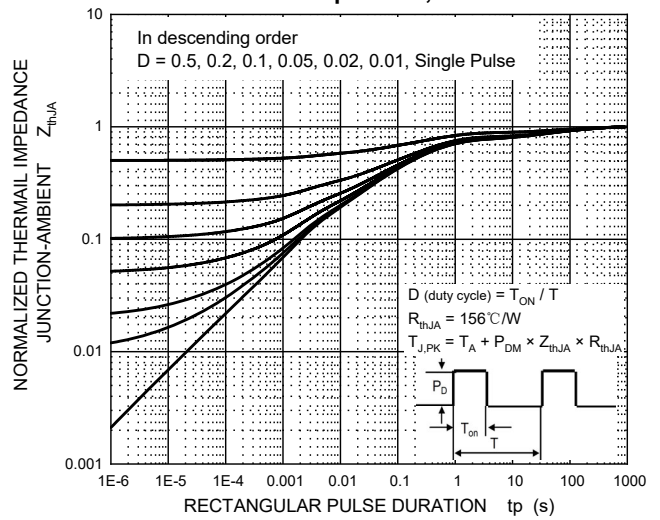
Drain-Source Breakdown Voltage



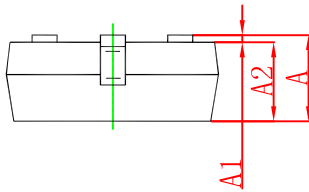
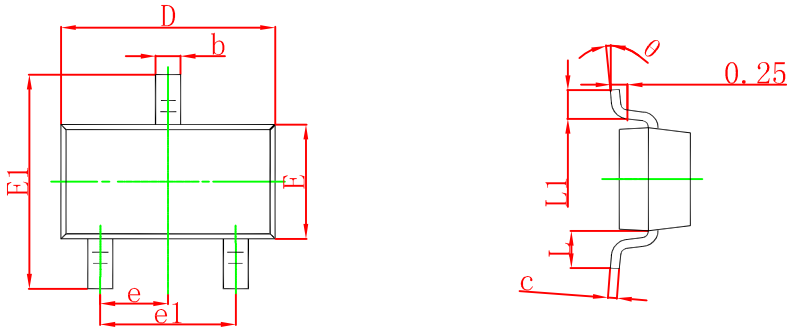
Maximum Safe Operating Area



Transient Thermal Impedance, Junction-Ambient

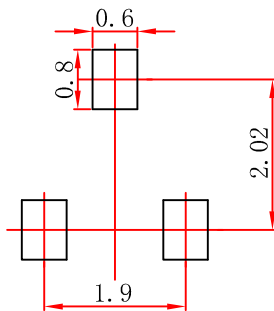


SOT-23 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

SOT-23 Suggested Pad Layout



Note:

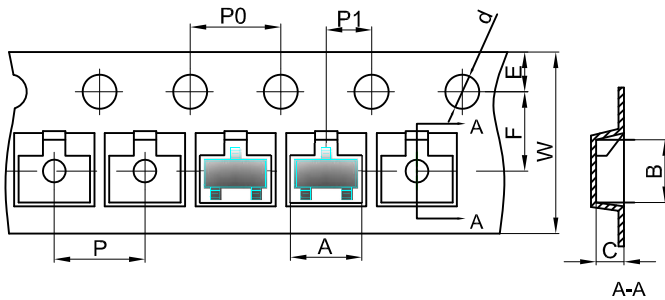
1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.

NOTICE

JSCJ reserves the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. JSCJ does not assume any liability arising out of the application or use of any product described herein.

SOT-23 Tape and Reel

SOT-23 Embossed Carrier Tape



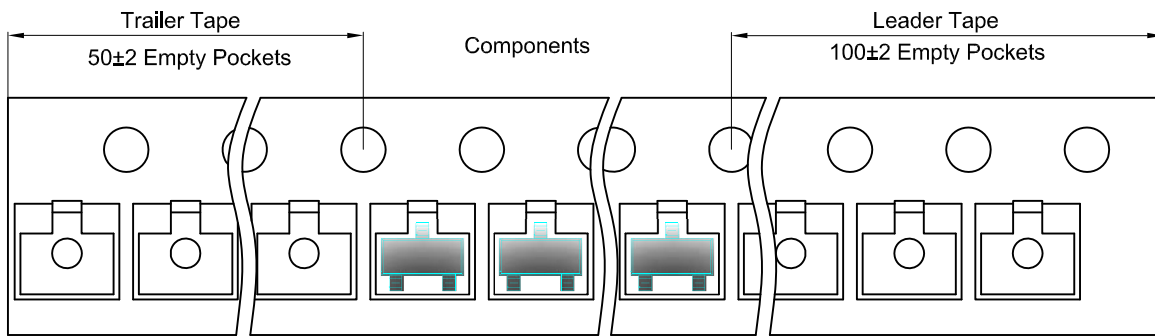
Packaging Description:

SOT-23 parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 3,000 units per 7" or 17.8cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).

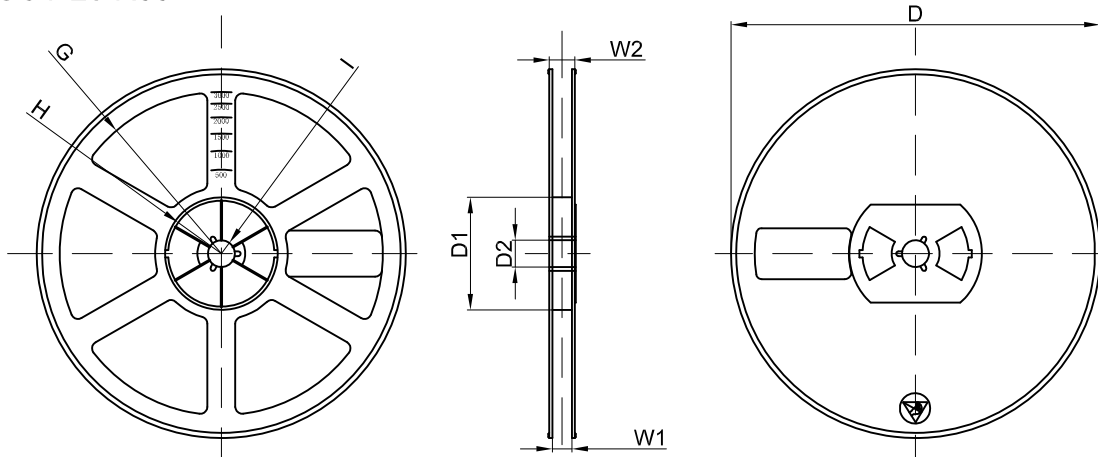
Dimensions are in millimeter

Pkg type	A	B	C	d	E	F	P0	P	P1	W
SOT-23	3.15	2.77	1.22	Ø1.50	1.75	3.50	4.00	4.00	2.00	8.00

SOT-23 Tape Leader and Trailer



SOT-23 Reel



Dimensions are in millimeter

Reel Option	D	D1	D2	G	H	I	W1	W2
7"D1a	Ø178,00	54,40	13,00	R78,00	R25,60	R6,50	9,50	12,30

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)	G.W.(kg)
3000 pcs	7 Inch	45,000 pcs	210×208×205	180,000 pcs	440×440×230	